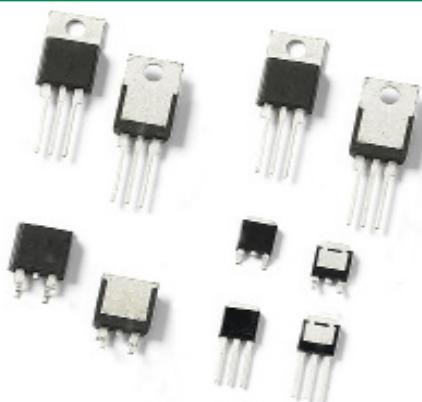
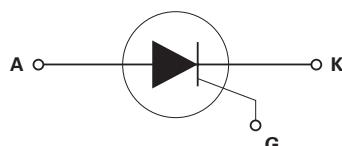


### SJxx12xx series



#### Schematic Symbol



#### Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
$V_{DRM}/V_{RRM}$	400 or 600	V
$I_{GT}$	6, 10 or 20	mA

#### Absolute Maximum Ratings

Symbol	Parameter	Test Conditions	Value	Unit
$V_{DSM}/V_{RSM}$	Peak non-repetitive blocking voltage	$Pw=100 \mu s$	$V_{DRM}/V_{RRM}+100$	V
$I_{T(RMS)}$	RMS on-state current	SJxx12Lx	$T_c = 110^\circ C$	12
		SJxx12Rx SJxx12Nx	$T_c = 135^\circ C$	
		SJxx12Dx SJxx12Vx	$T_c = 125^\circ C$	
$I_{T(AV)}$	Average on-state current	SJxx12Lx	$T_c = 110^\circ C$	7.6
		SJxx12Rx SJxx12Ny	$T_c = 135^\circ C$	
		SJxx12Dx SJxx12Vx	$T_c = 125^\circ C$	
$I_{TSM}$	Peak non-repetitive surge current (single half cycle, $T_j$ (initial) = 25°C)		$f = 50Hz$	100
			$f = 60Hz$	120
$I^2t$	$I^2t$ Value for fusing		$t_p = 8.3 \text{ ms}$	60
$di/dt$	Critical rate of rise of on-state current	$f = 60Hz; T_j = 150^\circ C$	100	$A/\mu s$
$I_{GM}$	Peak gate current	$T_j = 150^\circ C$	2	A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 150^\circ C$	0.5	W
$T_{stg}$	Storage temperature range		-40 to 150	$^\circ C$
$T_j$	Operating junction temperature range		-40 to 150	

Note: xx=voltage/10, x=sensitivity

SJxx12xx Series

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Specifications are subject to change without notice.

Revised: 02/16/18

# Thyristors

12 Amps High Junction Temperature SCRs

## Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified) - TO-220L, TO-220R and TO-263 package

Symbol	Test Conditions		SJxx12x	SJxx12x1	SJxx12x2	Unit
$I_{GT}$	$V_D = 12V$ $R_L = 60 \Omega$	MAX.	20	6	10	mA
		MIN.	8	2	5	
$V_{GT}$	$V_D = 12V$ $R_L = 60 \Omega$	MAX.	1.5	1.5	1.5	V
dv/dt	$V_D = 67\% V_{DRM}$ ; gate open; $T_J = 125^\circ\text{C}$	MIN.	800	70	500	V/ $\mu$ s
	$V_D = 67\% V_{DRM}$ ; gate open; $T_J = 150^\circ\text{C}$		400	-	200	
$V_{GD}$	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_J = 125^\circ\text{C}$	MIN.	0.2	0.2	0.2	V
$I_H$	$I_T = 200\text{mA}$ (initial)	MAX.	60	15	35	mA
$t_q$	$I_T = 2A$ ; $t_p = 50\mu\text{s}$ ; dv/dt = 5V/ $\mu$ s; di/dt = 30A/ $\mu$ s	MAX.	40	40	40	$\mu$ s
$t_{gt}$	$I_G = 2 \times I_{GT}$ PW = 15 $\mu$ s $I_T = 24\text{A}$	TYP.	2	2	2	$\mu$ s

Note: xx=voltage/10, x=package

## Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified) - TO-251 and TO-252 package

Symbol	Test Conditions	Value		Unit	
		SJxx12x1	SJxx12x		
$I_{GT}$	$V_D = 12V$ $R_L = 60 \Omega$	MAX.	6	mA	
		MIN.	2		
$V_{GT}$		MAX.	1.5	1.5	V
dv/dt	$V_D = V_{DRM}$ ; gate open; $T_J = 125^\circ\text{C}$	400V	100	250	V/ $\mu$ s
		600V	75	225	
	$V_D = V_{DRM}$ ; gate open; $T_J = 150^\circ\text{C}$	400V	50	200	
		600V	10	175	
$V_{GD}$	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_J = 125^\circ\text{C}$	MIN.	0.2	0.2	V
	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_J = 150^\circ\text{C}$	MIN.	0.1	0.1	
$I_H$	$I_T = 200\text{mA}$ (initial)	MAX.	20	40	mA
$t_q$	$I_T = 2A$ ; $t_p = 50\mu\text{s}$ ; dv/dt = 5V/ $\mu$ s; di/dt = 30A/ $\mu$ s	MAX.	35	35	$\mu$ s
$t_{gt}$	$I_G = 2 \times I_{GT}$ PW = 15 $\mu$ s $I_T = 12\text{A}$	TYP.	0.5	2	$\mu$ s

Note: xx=voltage/10, x=package

## Static Characteristics

Symbol	Test Conditions		Value	Unit
$V_{TM}$	Component $I_T = 24\text{A}$ ; $t_p = 380 \mu\text{s}$		1.6	V
$I_{DRM} / I_{RRM}$	$V_{DRM} = V_{RRM}$	$T_J = 25^\circ\text{C}$	10	$\mu$ A
		$T_J = 125^\circ\text{C}$	500	
		$T_J = 150^\circ\text{C}$	2000	

## Thermal Resistances

Symbol	Parameter	Value	Unit
$R_{\theta(JC)}$	Junction to case (AC)	SJxx12Lx	2.4
		SJxx12Rx SJxx12Nx	1.1
		SJxx12Dx SJxx12Vx	1.4
			°C/W

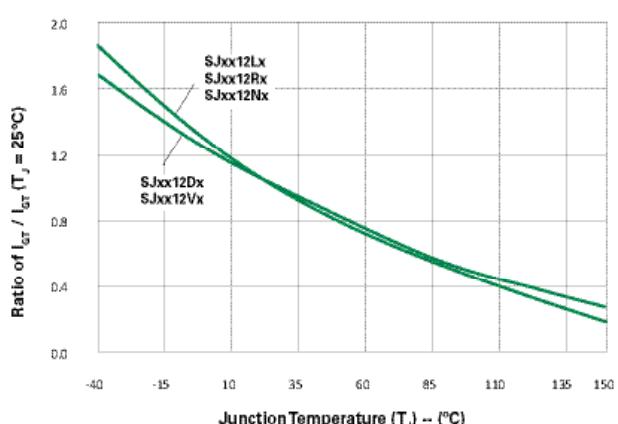
Note: xx=voltage/10, x=sensitivity

SJxx12xx Series

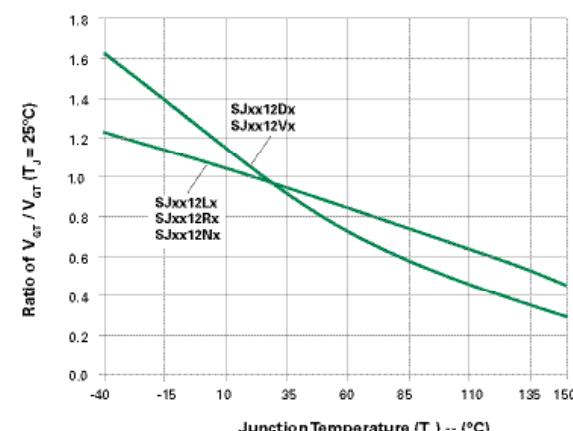
## Thyristors

12 Amps High Junction Temperature SCRs

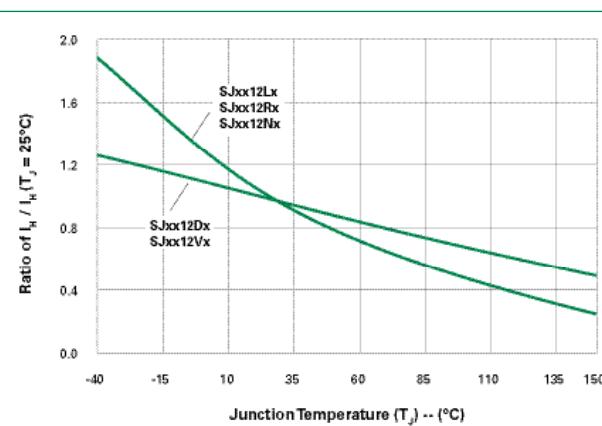
**Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature**



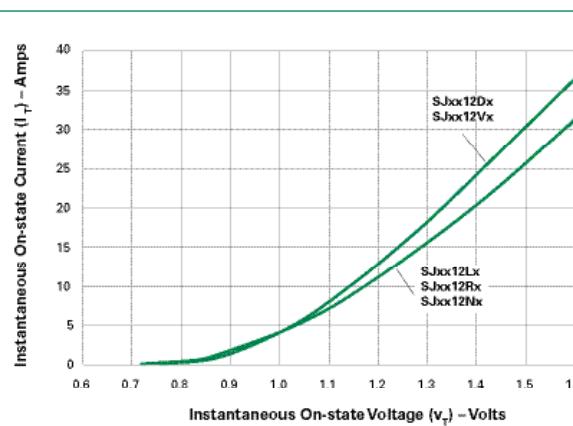
**Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature**



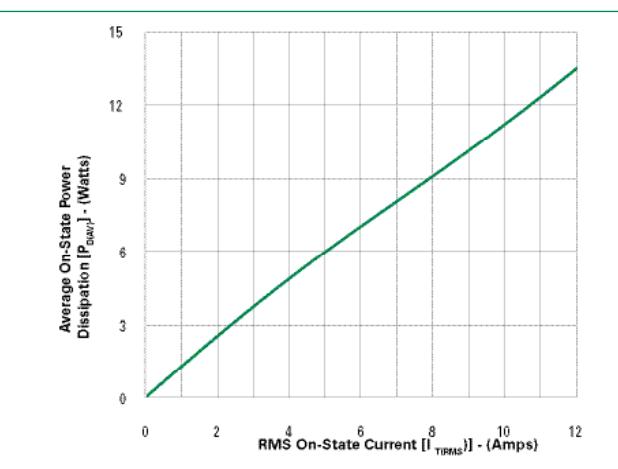
**Figure 3: Normalized DC Holding Current vs. Junction Temperature**



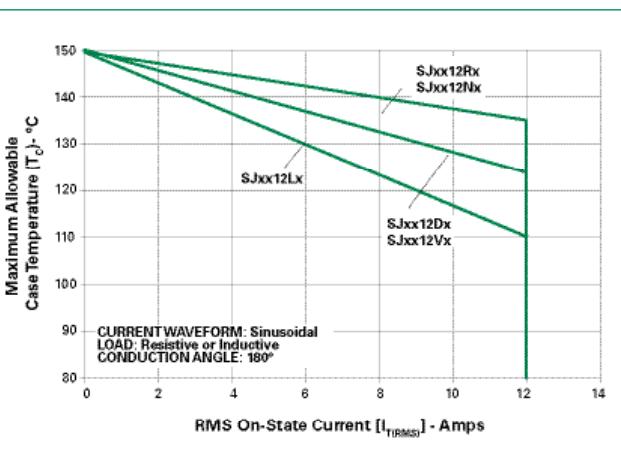
**Figure 4: On-State Current vs. On-State Voltage (Typical)**



**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current**



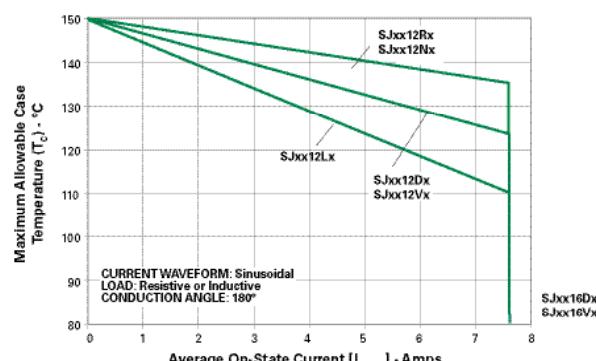
**Figure 6: Maximum Allowable Case Temperature vs. RMS On-state Current**



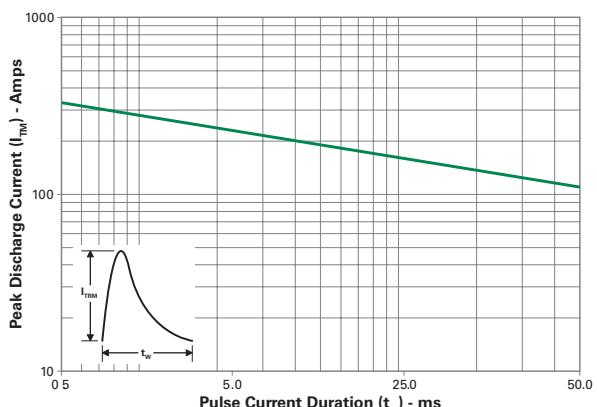
## Thyristors

12 Amps High Junction Temperature SCRs

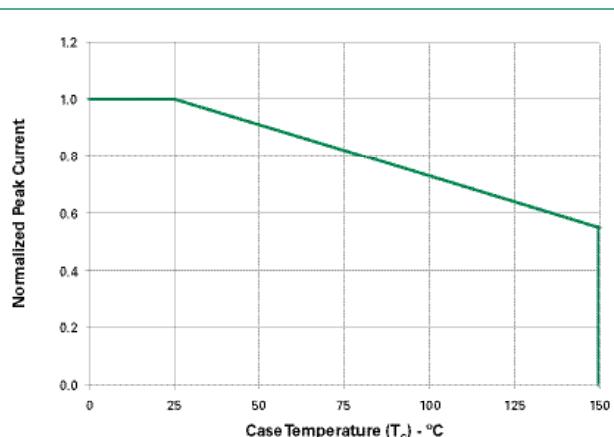
**Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current**



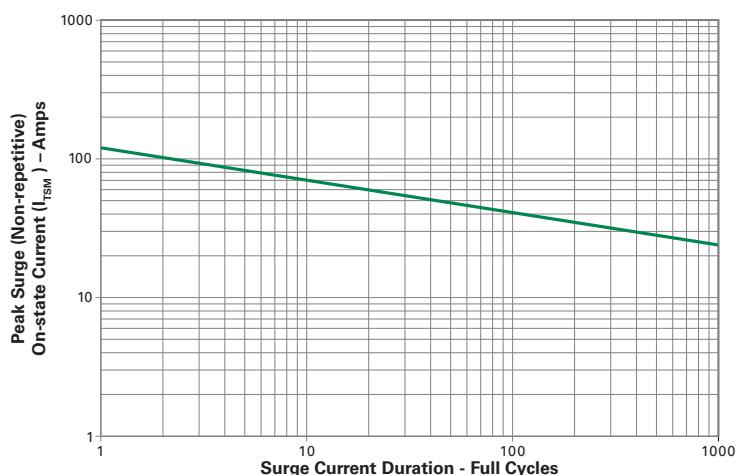
**Figure 8: Peak Capacitor Discharge Current**



**Figure 9: Peak Capacitor Discharge Current Derating**



**Figure 10: Surge Peak On-State Current vs. Number of Cycles**



SUPPLY FREQUENCY: 60 Hz Sinusoidal  
 LOAD: Resistive  
 RMS On-State Current: [ $I_{TRMS}$ ]: Maximum Rated Value at Specified Case Temperature

Notes:

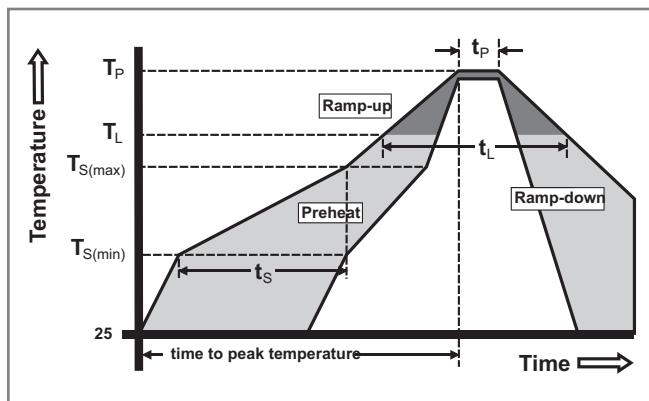
1. Gate control may be lost during and immediately following surge current interval.
2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

# Thyristors

## 12 Amps High Junction Temperature SCRs

### Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	150°C
	-Temperature Max ( $T_{s(max)}$ )	200°C
	-Time (min to max) ( $t_s$ )	60 – 180 secs
Average ramp up rate (Liquidus Temp) ( $T_L$ ) to peak		5°C/second max
$T_{S(max)}$ to $T_L$ - Ramp-up Rate		5°C/second max
Reflow	-Temperature ( $T_L$ ) (Liquidus)	217°C
	-Time ( $t_L$ )	60 – 150 seconds
Peak Temperature ( $T_p$ )		260 <sup>+0/-5</sup> °C
Time within 5°C of actual peak Temperature ( $t_p$ )		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature ( $T_p$ )		8 minutes Max.
Do not exceed		280°C



### Physical Specifications

<b>Terminal Finish</b>	100% Matte Tin-plated
<b>Body Material</b>	UL Recognized compound meeting flammability rating V-0.
<b>Lead Material</b>	Copper Alloy

### Environmental Specifications

Test	Specifications and Conditions
<b>AC Blocking</b>	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 150°C for 1008 hours
<b>Temperature Cycling</b>	MIL-STD-750, M-1051, 100 cycles; -55°C to +150°C; 15-min dwell-time
<b>Temperature/Humidity</b>	EIA / JEDEC, JESD22-A101 1008 hours; 160V - DC: 85°C; 85% rel humidity
<b>High Temp Storage</b>	MIL-STD-750, M-1031, 1008 hours; 150°C
<b>Low-Temp Storage</b>	1008 hours; -40°C
<b>Resistance to Solder Heat</b>	MIL-STD-750 Method 2031
<b>Solderability</b>	ANSI/J-STD-002, category 3, Test A
<b>Lead Bend</b>	MIL-STD-750, M-2036 Cond E
<b>Moisture Sensitivity Level</b>	Level 1, JEDEC-J-STD-020D

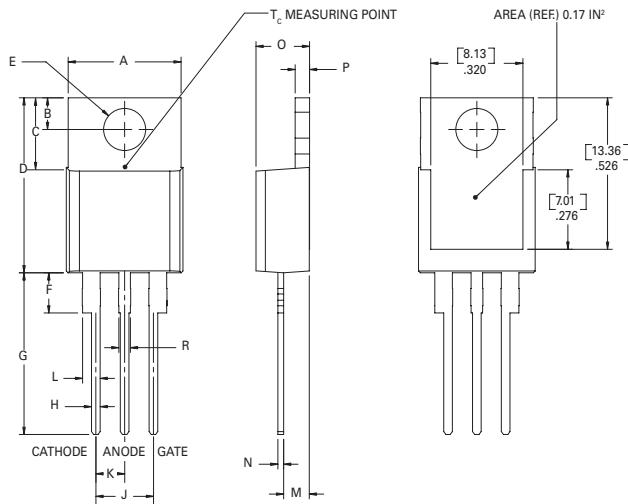
### Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

# Thyristors

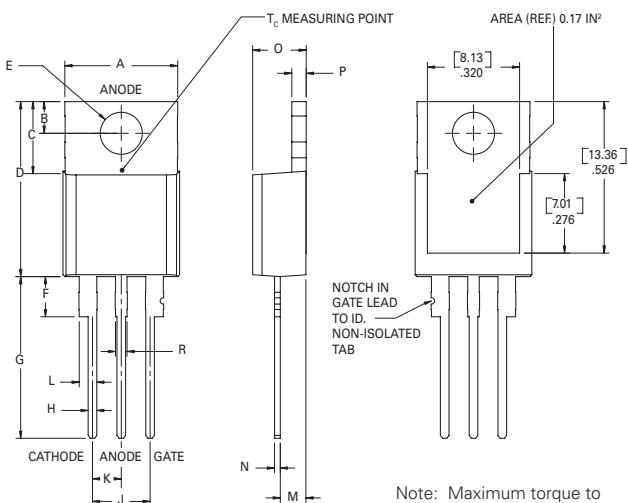
## 12 Amps High Junction Temperature SCRs

### Dimensions — TO-220AB (L-Package) — Isolated Mounting Tab



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

### Dimensions — TO-220AB (R-Package) — Non-Isolated Mounting Tab Common with Center Lead



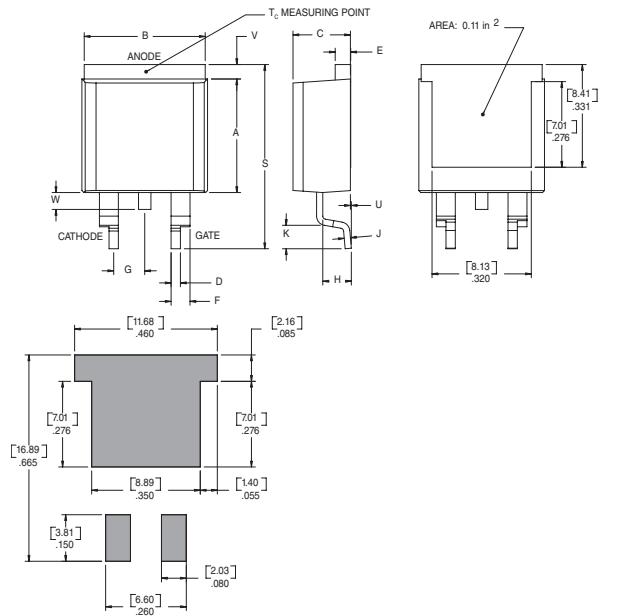
Note: Maximum torque to be applied to mounting tab is 8 in-lbs. (0.904 Nm).

Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

# Thyristors

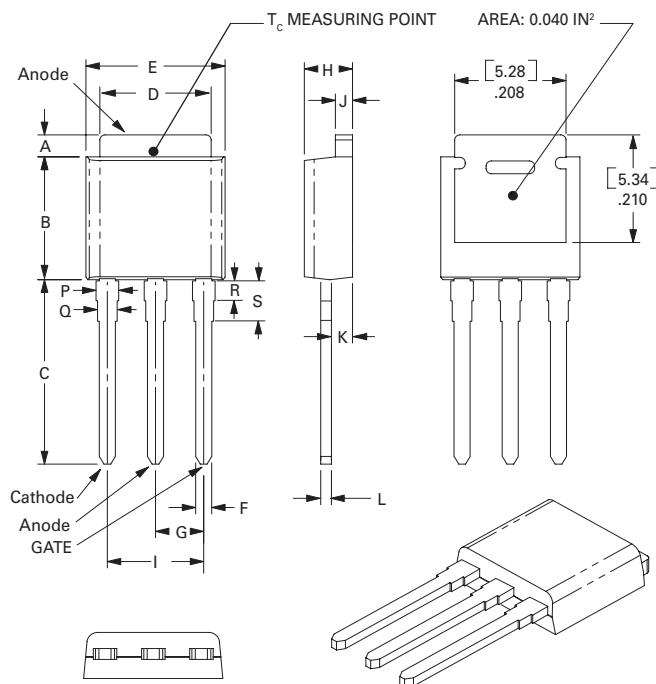
12 Amps High Junction Temperature SCRs

## Dimensions — TO- 263AB (N-package) — D<sup>2</sup>-Pak Surface Mount



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.360	0.370	9.14	9.40
B	0.380	0.420	9.65	10.67
C	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
E	0.045	0.060	1.14	1.52
F	0.060	0.075	1.52	1.91
G	0.095	0.105	2.41	2.67
H	0.092	0.102	2.34	2.59
J	0.018	0.024	0.46	0.61
K	0.090	0.110	2.29	2.79
S	0.590	0.625	14.99	15.88
V	0.035	0.045	0.89	1.14
U	0.002	0.010	0.05	0.25
W	0.040	0.070	1.02	1.78

## Dimensions — TO-251AA (V/I-Package) — V/I-PAK Through Hole

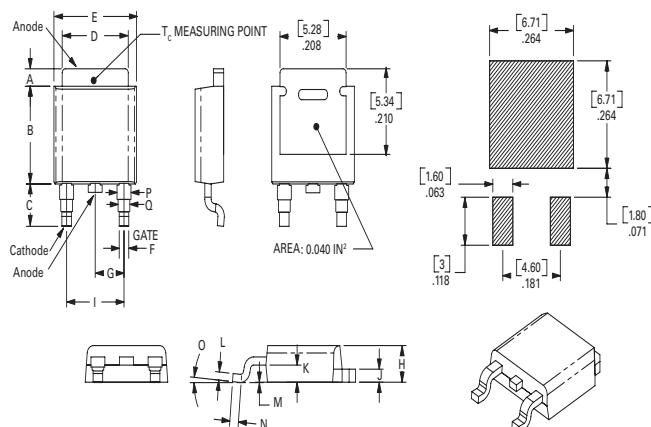


Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.040	0.044	0.050	1.02	1.11	1.27
B	0.235	0.242	0.245	5.97	6.15	6.22
C	0.350	0.361	0.375	8.89	9.18	9.53
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.66	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.34	2.41
I	0.176	0.180	0.184	4.47	4.57	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.038	0.040	0.044	0.97	1.01	1.12
L	0.018	0.020	0.023	0.46	0.52	0.58
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11
R	0.034	0.039	0.044	0.86	1.00	1.11
S	0.074	0.079	0.084	1.86	2.00	2.11

# Thyristors

12 Amps High Junction Temperature SCRs

## Dimensions — TO-252AA (D-Package) — D-PAK Surface Mount



Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.040	0.043	0.050	1.02	1.09	1.27
B	0.235	0.243	0.245	5.97	6.16	6.22
C	0.106	0.108	0.113	2.69	2.74	2.87
D	0.205	0.208	0.213	5.21	5.29	5.41
E	0.255	0.262	0.265	6.48	6.65	6.73
F	0.027	0.031	0.033	0.69	0.80	0.84
G	0.087	0.090	0.093	2.21	2.28	2.36
H	0.085	0.092	0.095	2.16	2.33	2.41
I	0.176	0.179	0.184	4.47	4.55	4.67
J	0.018	0.020	0.023	0.46	0.51	0.58
K	0.038	0.040	0.044	0.97	1.02	1.12
L	0.018	0.020	0.023	0.46	0.51	0.58
M	0.000	0.000	0.004	0.00	0.00	0.10
N	0.021	0.026	0.027	0.53	0.67	0.69
O	0°	0°	5°	0°	0°	5°
P	0.042	0.047	0.052	1.06	1.20	1.32
Q	0.034	0.039	0.044	0.86	1.00	1.11

## Product Selector

Part Number	Voltage		Gate Sensitivity	Type	Package
	400V	600V			
SJxx12L	X	X	20mA	Standard SCR	TO-220L
SJxx12R	X	X	20mA	Standard SCR	TO-220R
SJxx12N	X	X	20mA	Standard SCR	TO-263
SJxx12V	X	X	20mA	Standard SCR	TO-251
SJxx12D	X	X	20mA	Standard SCR	TO-252
SJxx12L1	X	X	6mA	Standard SCR	TO-220L
SJxx12R1	X	X	6mA	Standard SCR	TO-220R
SJxx12N1	X	X	6mA	Standard SCR	TO-263
SJxx12V1	X	X	6mA	Standard SCR	TO-251
SJxx12D1	X	X	6mA	Standard SCR	TO-252
SJxx12L2	X	X	10mA	Standard SCR	TO-220L
SJxx12R2	X	X	10mA	Standard SCR	TO-220R
SJxx12N2	X	X	10mA	Standard SCR	TO-263

Note: xx = Voltage/10

# Thyristors

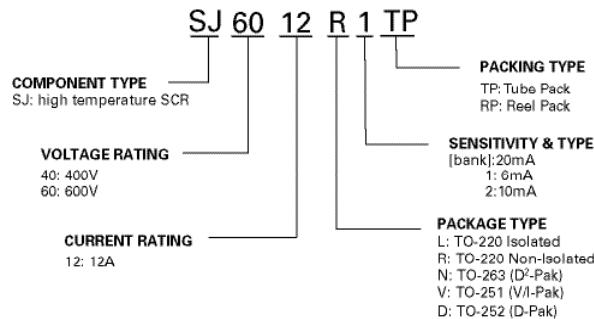
## 12 Amps High Junction Temperature SCRs

### Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
SJxx12LxTP	SJxx12Ly	2.2g	Tube	500 (50 per tube)
SJxx12RxTP	SJxx12Ry	2.2g	Tube	500 (50 per tube)
SJxx12NxTP	SJxx12Ny	1.6g	Tube	500 (50 per tube)
SJxx12NxRP	SJxx12Ny	1.6g	Embossed Carrier	500
SJxx12DxTP	SJxx12Dx	0.3 g	Tube	750 (75 per tube)
SJxx12DxRP	SJxx12Dx	0.3 g	Embossed Carrier	2500
SJxx12VxTP	SJxx12Vx	0.4 g	Tube	750 (75 per tube)

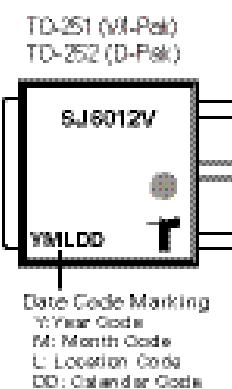
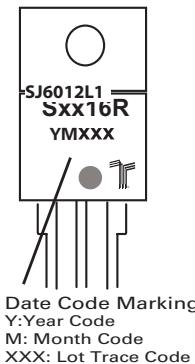
Note: xx=voltage/10, x=sensitivity

### Part Numbering System



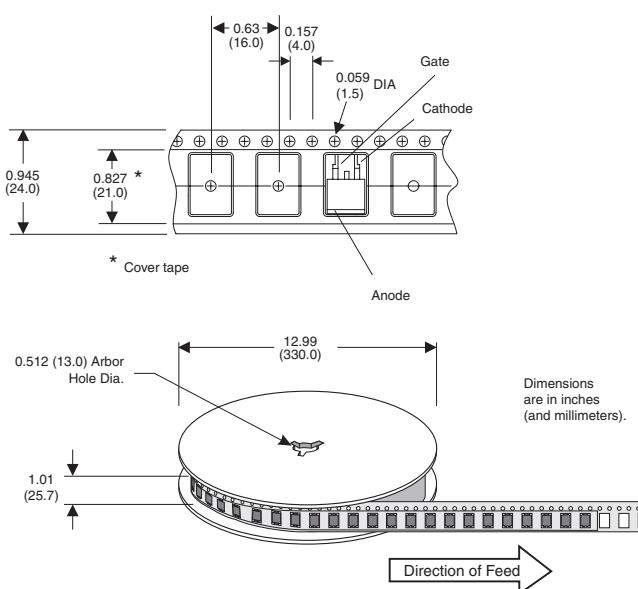
### Part Marking System

TO-220 AB - (L and R Package)  
TO-263 AB - (N Package)



### TO-263 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards

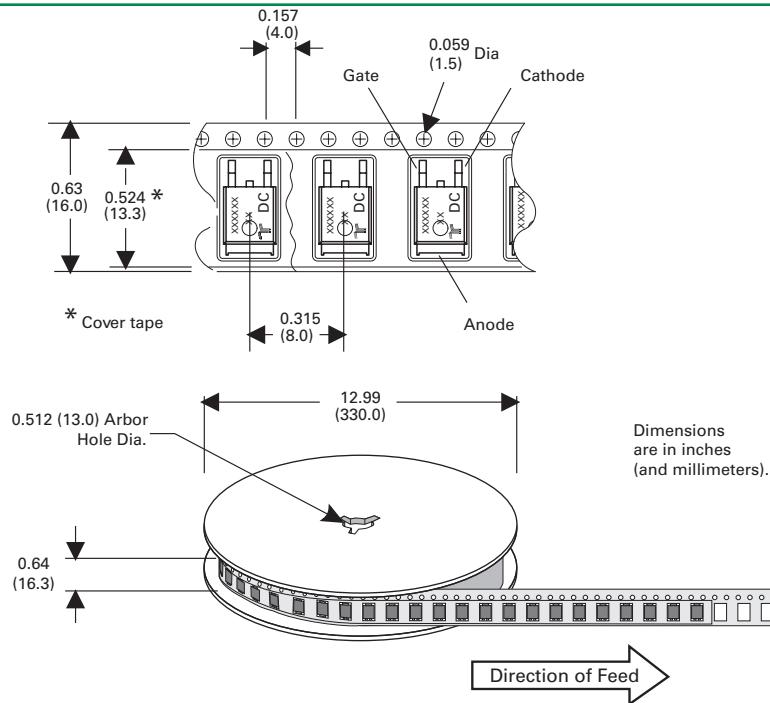


## Thyristors

12 Amps High Junction Temperature SCRs

### TO-252 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards



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